Schottky Barrier Diode

RB078BM30S

Data Sheet

●Application

General Rectification

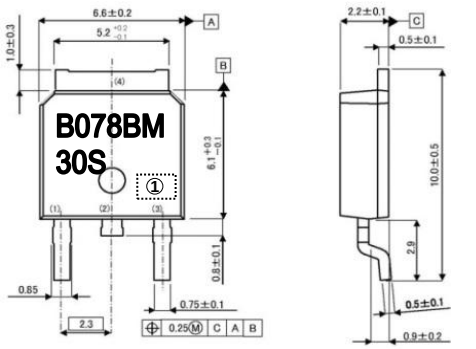
●Features

1) Power mold type (TO-252)
2) High reliability
3) Low V_F

●Construction

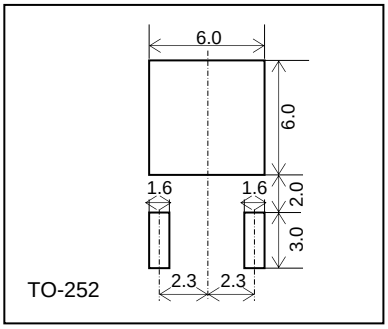
Silicon epitaxial planar type

●Dimensions (Unit : mm)

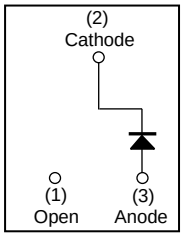


ROHM : TO-252
JEITA : SC-63
① : Manufacture Date

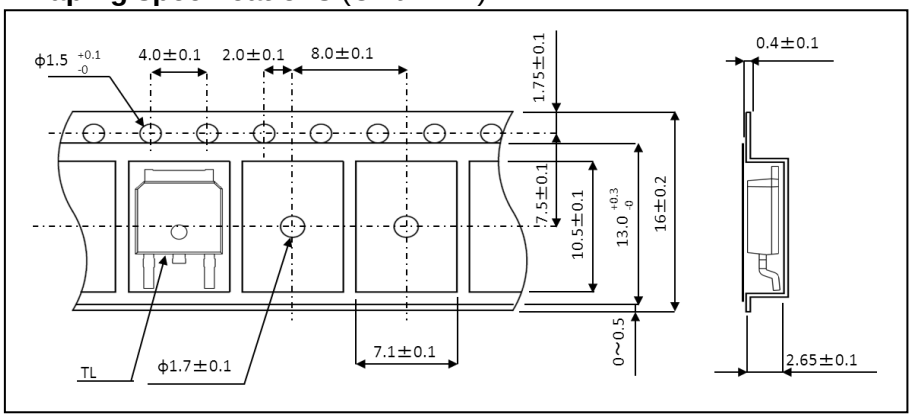
●Land size figure (Unit : mm)



●Structure



●Taping specifications (Unit : mm)



●Absolute maximum ratings (T_c= 25°C)

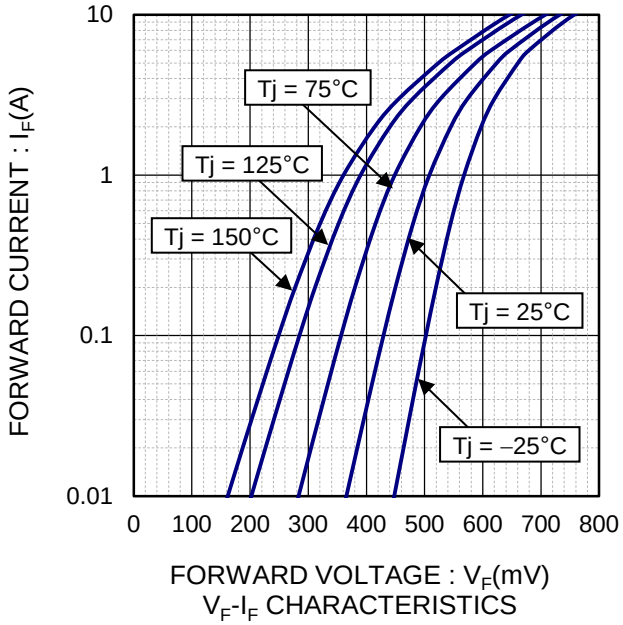
Parameter	Symbol	Limits	Unit	Conditions
Repetitive Peak Reverse Voltage	V_{RM}	30	V	Duty≦0.5
Reverse Voltage	V_R	30	V	Direct Reverse Voltage
Average forward rectified current	I_o	5	A	60Hz half sin Wave resistive load, T_c=126°C max.
Non-repetitive Forward Current Surge Peak	I_{FSM}	50	A	60Hz half sin wave, Non-repetitive at T_a=25ºC
Operating Junction Temperature	T_j	150	°C	-
Storage Temperature	T_{stg}	−55 to +150	°C	-

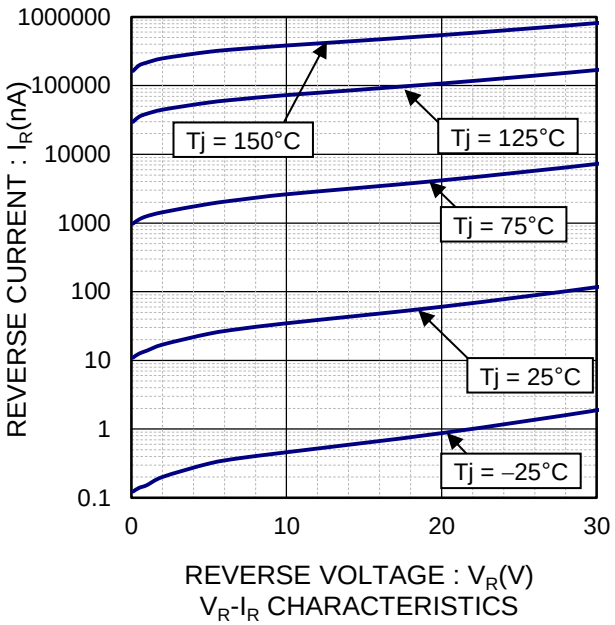
●Electrical characteristics (T_j = 25°C)

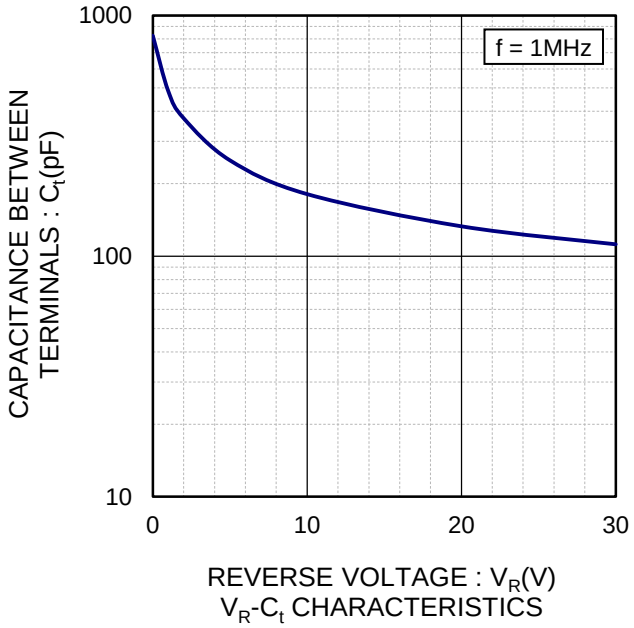
Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward voltage	V_F	-	-	0.72	V	I_F=5.0A
Reverse current	I_R	-	-	5	μA	V_R=30V

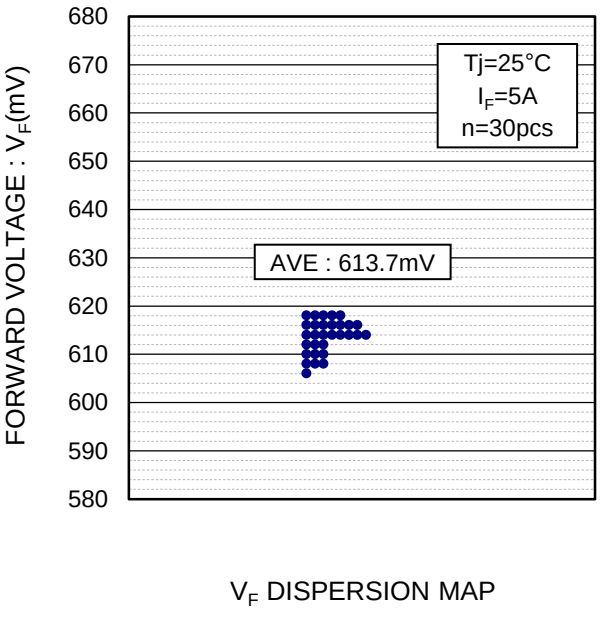
© 2014 ROHM Co., Ltd. All rights reserved.

●Electrical characteristic curves



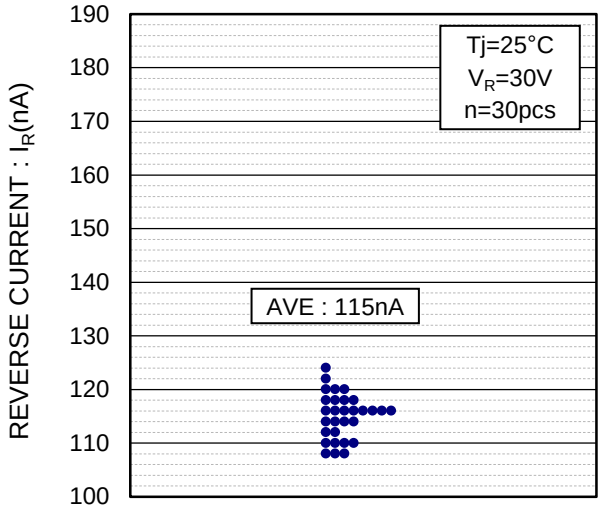




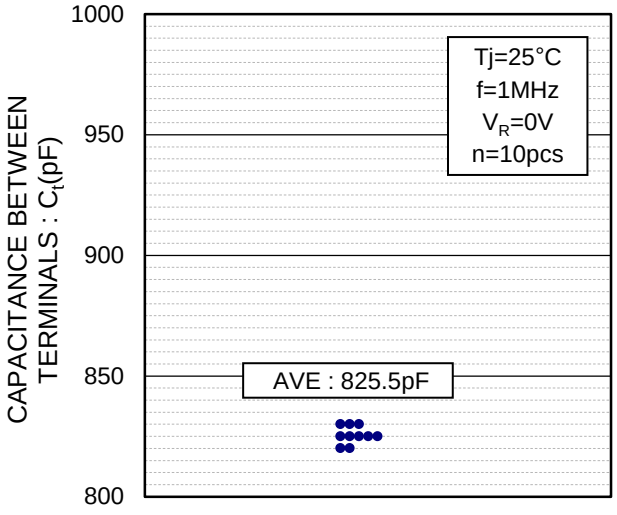


© 2014 ROHM Co., Ltd. All rights reserved.

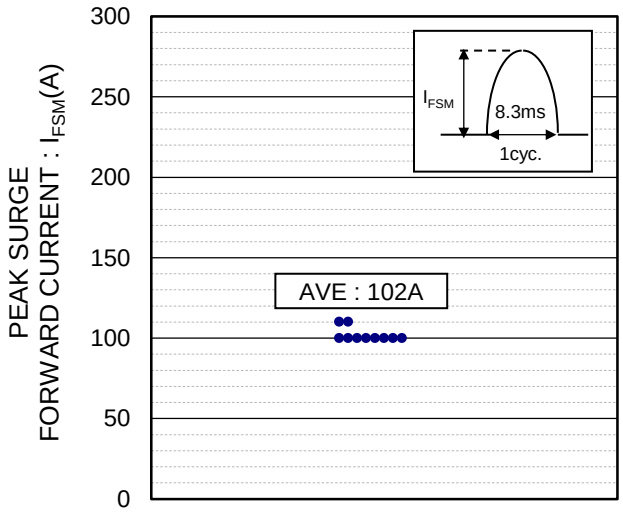
●Electrical characteristic curves



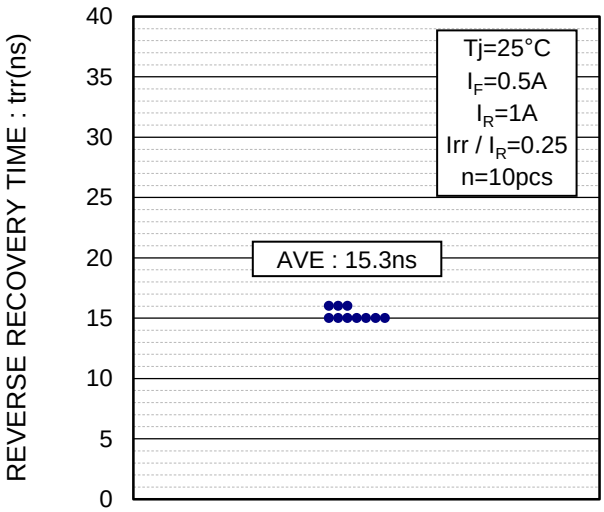
I_R DISPERSION MAP



C_t DISPERSION MAP



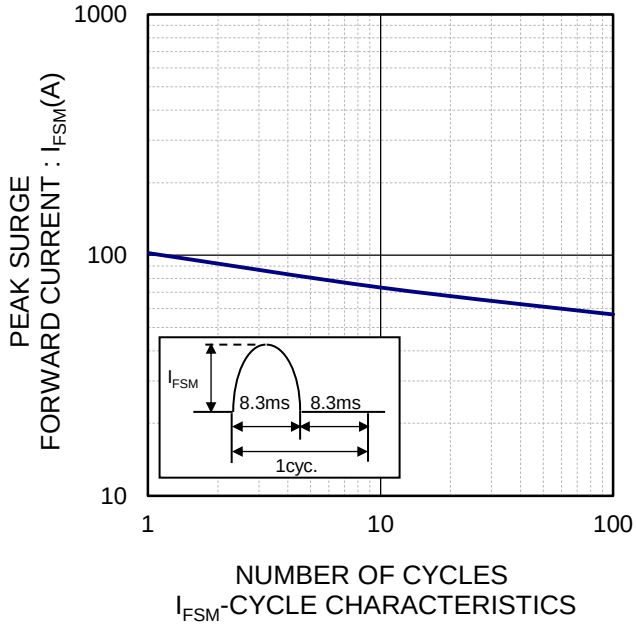
I_{FSM} DISPERSION MAP

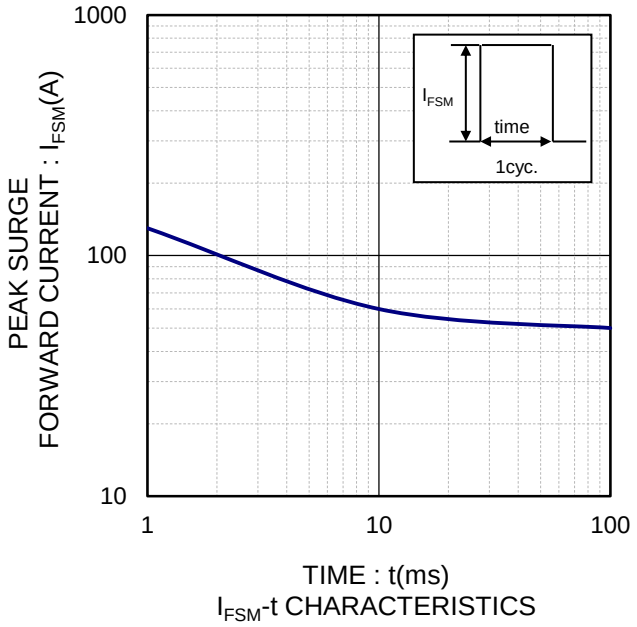


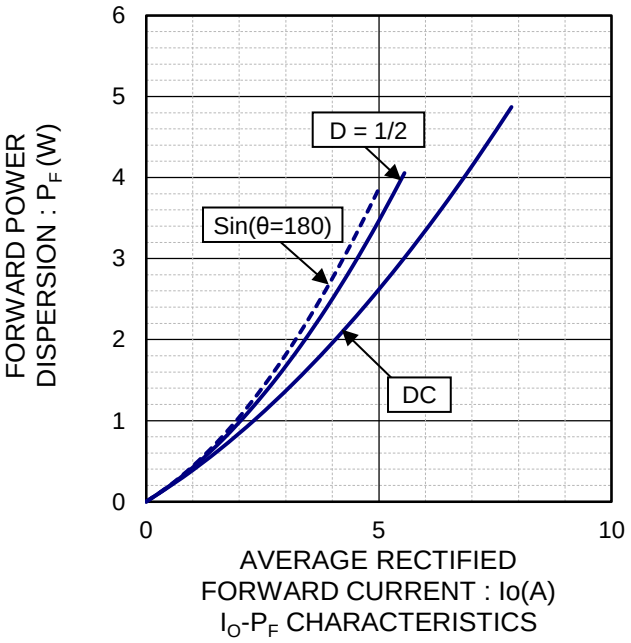
trr DISPERSION MAP

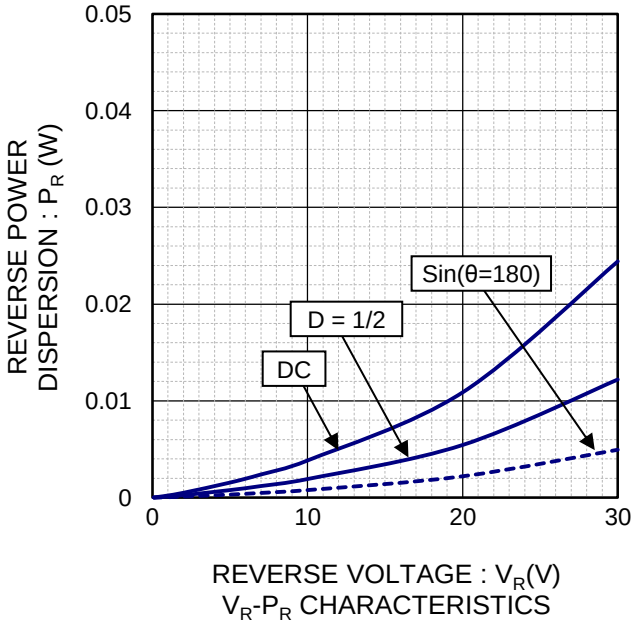
© 2014 ROHM Co., Ltd. All rights reserved.

●Electrical characteristic curves



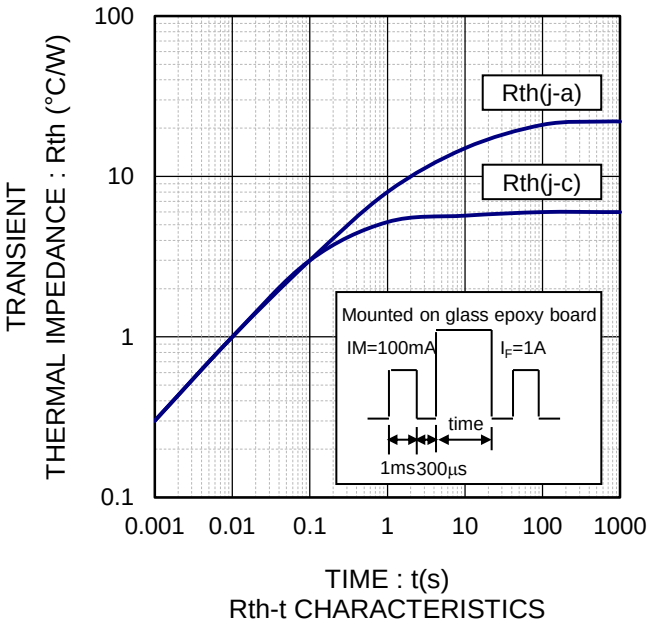




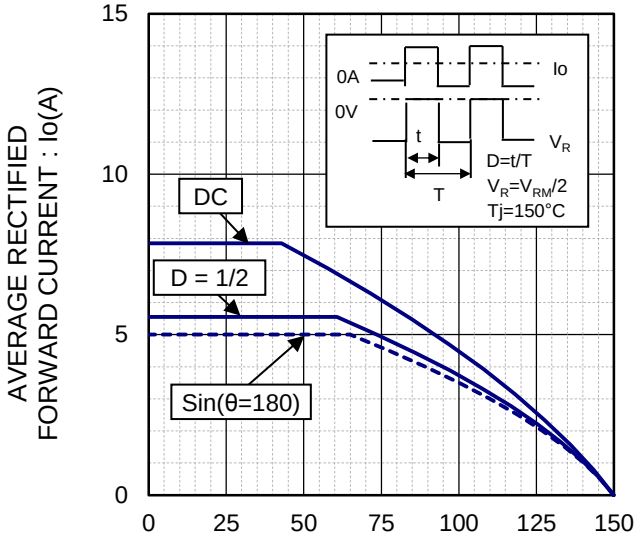


© 2014 ROHM Co., Ltd. All rights reserved.

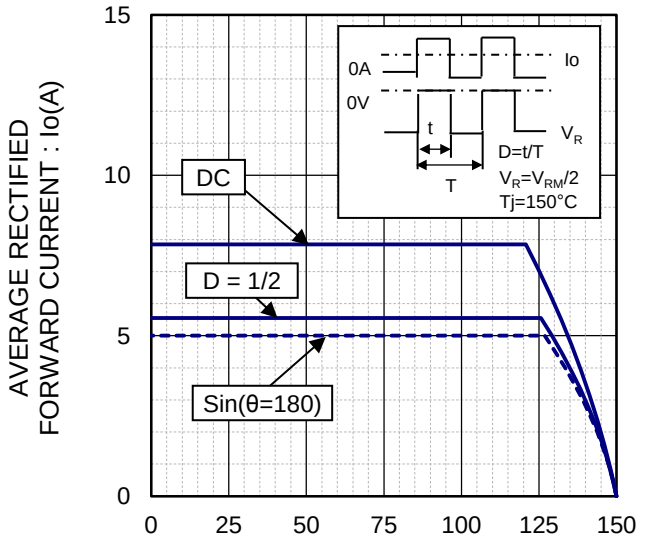
●Electrical characteristic curves



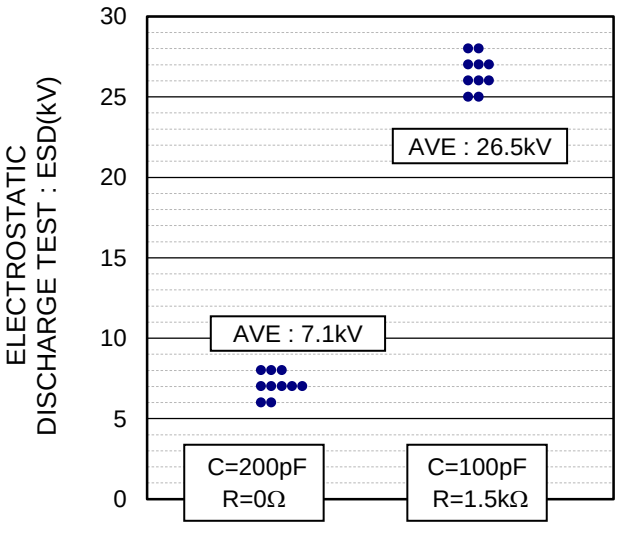
Rth-t CHARACTERISTICS



DERATING CURVE (Io-Ta)



DERATING CURVE (Io-Tc)



ESD DISPERSION MAP

© 2014 ROHM Co., Ltd. All rights reserved.

Notes

1) The information contained herein is subject to change without notice.

2) Before you use our Products, please contact our sales representative and verify the latest specifications :

3) Although ROHM is continuously working to improve product reliability and quality, semiconductors can break down and malfunction due to various factors.
Therefore, in order to prevent personal injury or fire arising from failure, please take safety measures such as complying with the derating characteristics, implementing redundant and fire prevention designs, and utilizing backups and fail-safe procedures. ROHM shall have no responsibility for any damages arising out of the use of our Poducts beyond the rating specified by ROHM.

4) Examples of application circuits, circuit constants and any other information contained herein are provided only to illustrate the standard usage and operations of the Products. The peripheral conditions must be taken into account when designing circuits for mass production.

5) The technical information specified herein is intended only to show the typical functions of and examples of application circuits for the Products. ROHM does not grant you, explicitly or implicitly, any license to use or exercise intellectual property or other rights held by ROHM or any other parties. ROHM shall have no responsibility whatsoever for any dispute arising out of the use of such technical information.

6) The Products are intended for use in general electronic equipment (i.e. AV/OA devices, communication, consumer systems, gaming/entertainment sets) as well as the applications indicated in this document.

7) The Products specified in this document are not designed to be radiation tolerant.

8) For use of our Products in applications requiring a high degree of reliability (as exemplified below), please contact and consult with a ROHM representative : transportation equipment (i.e. cars, ships, trains), primary communication equipment, traffic lights, fire/crime prevention, safety equipment, medical systems, servers, solar cells, and power transmission systems.

9) Do not use our Products in applications requiring extremely high reliability, such as aerospace equipment, nuclear power control systems, and submarine repeaters.

10) ROHM shall have no responsibility for any damages or injury arising from non-compliance with the recommended usage conditions and specifications contained herein.

11) ROHM has used reasonable care to ensur the accuracy of the information contained in this document. However, ROHM does not warrants that such information is error-free, and ROHM shall have no responsibility for any damages arising from any inaccuracy or misprint of such information.

12) Please use the Products in accordance with any applicable environmental laws and regulations, such as the RoHS Directive. For more details, including RoHS compatibility, please contact a ROHM sales office. ROHM shall have no responsibility for any damages or losses resulting non-compliance with any applicable laws or regulations.

13) When providing our Products and technologies contained in this document to other countries, you must abide by the procedures and provisions stipulated in all applicable export laws and regulations, including without limitation the US Export Administration Regulations and the Foreign Exchange and Foreign Trade Act.

14) This document, in part or in whole, may not be reprinted or reproduced without prior consent of ROHM.

ROHM SEMICONDUCTOR

Thank you for your accessing to ROHM product informations.
More detail product informations and catalogs are available, please contact us.

ROHM Customer Support System

http://www.rohm.com/contact/

© 2014 ROHM Co., Ltd. All rights reserved.